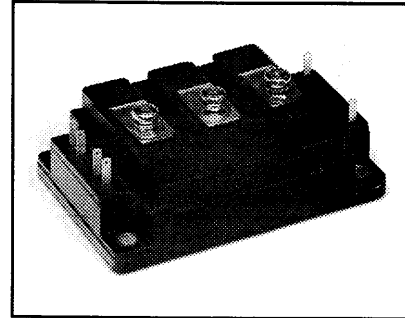
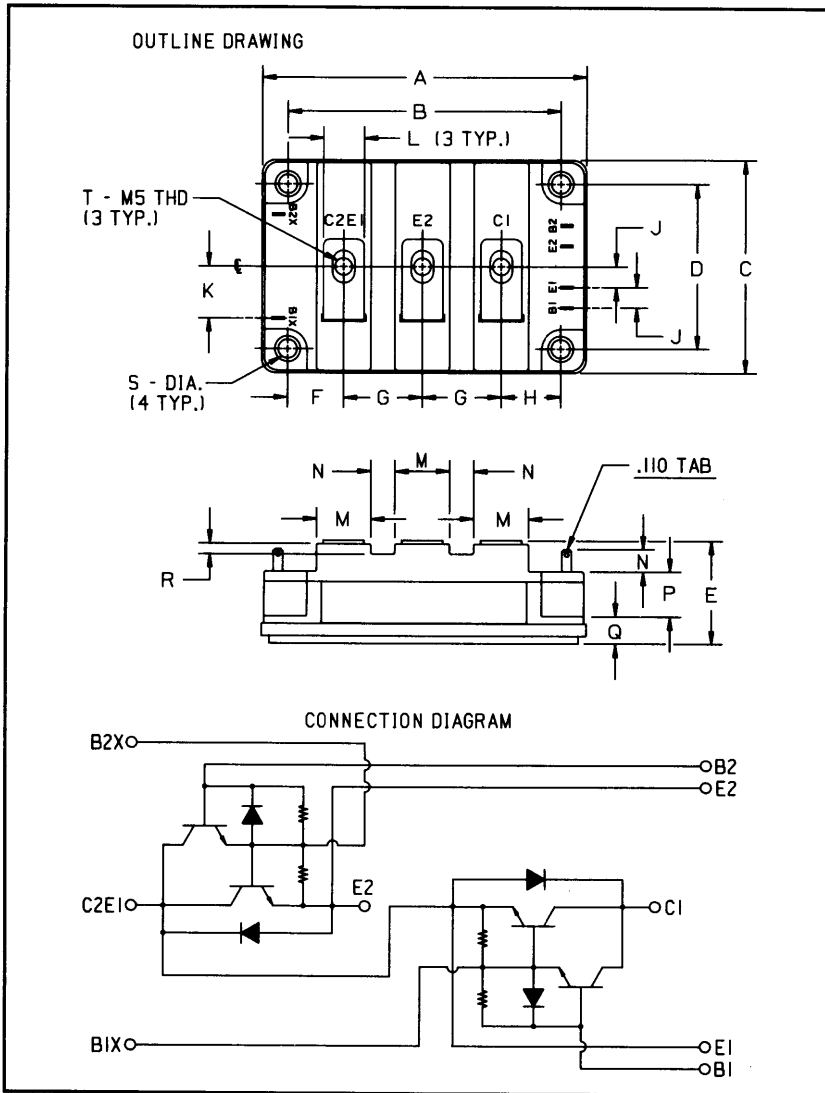


### Dual Darlington Transistor Module 150 Amperes/600 Volts



#### Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

#### Features:

- Isolated Mounting
- Planar Chips
- Discrete Fast Recovery Feedback Diode
- High Gain ( $h_{FE}$ )
- Quick Connect Base-Emitter Signal Terminals
- Base-Emitter Speed-up Diodes

#### Applications:

- AC Motor Control
- DC Motor Control
- Switching Power Supplies
- Inverters

#### Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KD324515 is a 450  $V_{CE0(sus)}$  (600  $V_{CEV}$ ), 150 Ampere Dual Darlington Module.

Outline Drawing

Dimensions	Inches	Millimeters
A	3.740 Max.	95 Max.
B	3.150 ± 0.01	80 ± 0.25
C	2.441 Max.	62 Max.
D	1.890 ± 0.01	48 ± 0.25
E	1.181 Max.	30 Max.
F	0.650	16.5
G	0.906	23
H	0.689	17.5
J	0.236	6

Dimensions	Inches	Millimeters
K	0.596	15
L	0.472	12
M	0.630	16
N	0.276	7
P	0.512	13
Q	0.315	8
R	0.118	3
S	0.216 Dia.	5.5 Dia.
T	M5 Metric	M5

Type	$V_{CE0(sus)}$ Volts (X 10)	Current Rating Amperes (X 10)
KD32	45	15



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

**KD324515**  
**Dual Darlington Transistor Module**  
 150 Amperes/600 Volts

**Absolute Maximum Ratings,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	KD324515	Units
Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage	$V_{CEO(sus)}$	450	Volts
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	600	Volts
Collector-Base Voltage	$V_{CBO}$	600	Volts
Emitter-Base Voltage	$V_{EBO}$	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	$V_{CEV}$	600	Volts
Continuous Collector Current	$I_C$	150	Amperes
Diode Forward Current	$I_{FM}$	150	Amperes
Continuous Base Current	$I_B$	9	Amperes
Diode Surge Current	$I_{FSM}$	1500	Amperes
Power Dissipation (Each Transistor)	$P_t$	690	Watts
Max. Mounting Torque M5 Terminal Screws	-	17	in.-lb.
Max. Mounting Torque M5 Mounting Screws	-	17	in.-lb.
Module Weight (Typical)	-	420	Grams
V Isolation	$V_{RMS}$	2500	Volts

**Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Collector Cutoff Current	$I_{CEV}$	$V_{CE} = 600\text{V}, V_{BE} = -2\text{V}$	-	-	2	mA	
		$V_{CE} = 600\text{V}, V_{BE} = -2\text{V}, T_C = 125^\circ\text{C}$	-	-	15	mA	
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 7\text{V}$	-	-	300	mA	
DC Current Gain	$h_{FE}$	$I_C = 150\text{A}, V_{CE} = 2\text{V}$	75	-	-	-	
		$I_C = 150\text{A}, V_{CE} = 5\text{V}$	100	-	-	-	
Diode Forward Voltage	$V_{FM}$	$I_{FM} = 150\text{A}$	-	-	1.85	Volts	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 150\text{A}, I_B = 2\text{A}$	-	-	2.0	Volts	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 150\text{A}, I_B = 2\text{A}$	-	-	2.5	Volts	
Resistive	Turn-on	$t_{on}$	$V_{CC} = 300\text{V}$	-	-	2.5	$\mu\text{s}$
Load	Storage Time	$t_s$	$I_C = 150\text{A}$	-	-	12	$\mu\text{s}$
Switch Times	Fall Time	$t_f$	$I_{B1} = 2\text{A}, I_{B2} = -2\text{A}$	-	-	3.0	$\mu\text{s}$

**Thermal and Mechanical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Case-to-Sink	$R_{\theta(c-s)}$	Per 1/2 Module	-	-	0.1	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	-	-	0.18	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	-	-	0.6	$^\circ\text{C/W}$